

**Digital Attenuator,
31.0 dB, 5-Bit, TTL Driver, DC-6.0 GHz**

**AT90-0001
V9**

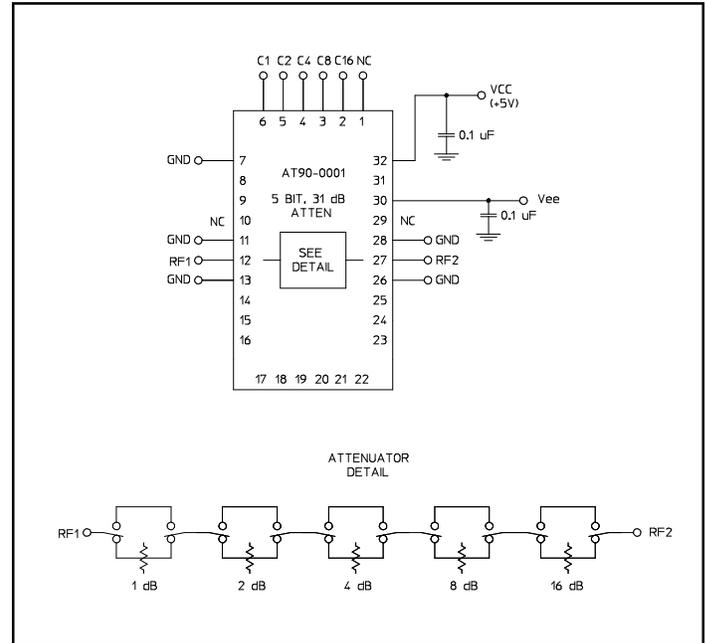
Features

- Attenuation: 1.0 dB Steps to 31 dB
- High Accuracy to 6 GHz
- Small Footprint, JEDEC Package
- Integral TTL driver
- 50 ohm impedance
- Test boards are available
- Tape and Reel Packaging Available

Description

M/A-COM's AT90-0001 is a GaAs FET 5-bit digital attenuator with an integral TTL driver. Step size is 1.0 dB providing 31 dB total attenuation range. This device is in a 32 lead FQFP-N surface mount package. Due to superior grounding techniques this digital attenuator offers superior performance to 6 GHz. The AT90-0001 is ideally suited for use where accuracy, fast speed, very low power consumption and low costs are required.

Functional Schematic



Pin Configuration¹

Pin No.	Function	Pin No.	Function
1	NC	17	NC
2	C16	18	NC
3	C8	19	NC
4	C4	20	NC
5	C2	21	NC
6	C1	22	NC
7	GND	23	NC
8	NC	24	NC
9	NC	25	NC
10	NC ²	26	GND
11	GND	27	RF2
12	RF1	28	GND
13	GND	29	NC ²
14	NC	30	-Vee
15	NC	31	NC
16	NC	32	+Vcc

1. The exposed pad centered on the package bottom must be connected to RF and DC ground. (For PQFN Packages)
2. Pins 10 and 29 must be isolated.

Ordering Information

Part Number	Package
AT90-0001	Bulk Packaging
AT90-0001TR	1000 piece reel
AT90-0001-TB	Sample Test Board

Note: Reference Application Note M513 for reel size information.

Note: Die quantity varies.

* Restrictions on Hazardous Substances, European Union Directive

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Electrical Specifications: $T_A = 25^\circ\text{C}$, $Z_0 = 50\Omega$, $V_{cc} = 5.0\text{V}$, $V_{ee} = -5.0\text{V}$

Parameter	Test Conditions	Frequency	Units	Min	Typ	Max
Insertion Loss	—	DC - 2.0 GHz	dB	—	2.5	3.1
		DC - 4.0 GHz	dB	—	3.3	3.8
		DC - 6.0 GHz	dB	—	5.0	5.8
Attenuation Accuracy	1 to 24 dB Bits	DC - 6.0 GHz	dB	—	—	$\pm(0.3 + 4\% \text{ of atten.})$
	25 to 31 dB Bits	DC - 6.0 GHz	dB	—	—	$\pm(0.3 + 5\% \text{ of atten.})$
VSWR	Full Range	DC - 2.0 GHz	Ratio	—	1.4:1	1.7:1
		DC - 6.0 GHz	Ratio	—	1.7:1	2.4:1
1 dB Compression	—	50 MHz	dBm	—	+22	—
		0.5 - 6.0 GHz	dBm	—	+24	—
Input IP2	Two tone inputs to +5 dBm	50 MHz	dBm	—	+43	—
		0.5 - 6.0 GHz	dBm	—	+60	—
Input IP3	Two-tone inputs up to +5 dBm	50 MHz	dB	—	+37	—
		0.5-6.0 GHz	dB	—	+48	—
V _{cc}	—	—	V	4.75	5.0	5.25
V _{ee}	—	—	V	-8.0	-5.0	-4.75
Switching Speed	50% Cntl to 90%/10% RF 10% to 90% or 90% to 10%	—	ns	—	25	—
		—	ns	—	15	—
V _{IL}	LOW-level input voltage	—	V	0.0	-	0.8
V _{IH}	HIGH-level input voltage	—	V	2.0	-	5.0
I _{in} (Input Leakage Current)	V _{in} = V _{cc} or GND	—	uA	-1.0	-	1.0
I _{cc} (Quiescent Supply Current)	V _{cntrl} = V _{cc} or GND	—	uA	—	250	400
ΔI_{cc}^3 (Additional Supply Current Per TTL Input Pin)	V _{cc} = Max, V _{cntrl} = V _{cc} - 2.1V	—	mA	—	—	1.0
I _{ee}	V _{ee} min to max, V _{in} = V _{IL} or V _{IH}	—	mA	-1.0	-0.2	-
Thermal Resistance θ_{jc}	—	—	°C/W	—	15	—

3. The 16 dB bit is connected to two driver input pins, so ΔI_{cc} needs to be calculated based on 6 TTL inputs.

Truth Table (Digital Attenuator)

C16	C8	C4	C2	C1	Attenuation
0	0	0	0	0	Loss, Reference
0	0	0	0	1	1 dB
0	0	0	1	0	2 dB
0	0	1	0	0	4 dB
0	1	0	0	0	8 dB
1	0	0	0	0	16 dB
1	1	1	1	1	31 dB

0 = TTL Low; 1 = TTL High

Absolute Maximum Ratings^{4,5}

Parameter	Absolute Maximum
Max. Input Power 0.05 GHz 0.5 - 6.0 GHz	+27 dBm +34 dBm
V _{cc}	-0.5V ≤ V _{cc} ≤ +7.0V
V _{ee}	-8.5V ≤ V _{ee} ≤ +0.5V
V _{cc} - V _{ee}	-0.5V ≤ V _{cc} - V _{ee} ≤ 14.5V
V _{in} ⁶	-0.5V ≤ V _{in} ≤ V _{cc} + 0.5V
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +125°C

4. Exceeding any one or combination of these limits may cause permanent damage to this device.
 5. M/A-COM does not recommend sustained operation near these survivability limits.
 6. Standard CMOS TTL interface, latch-up will occur if logic signal is applied prior to power supply.

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Handling Procedures

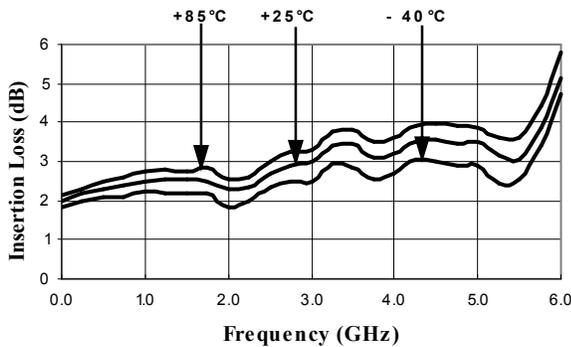
Please observe the following precautions to avoid damage:

Static Sensitivity

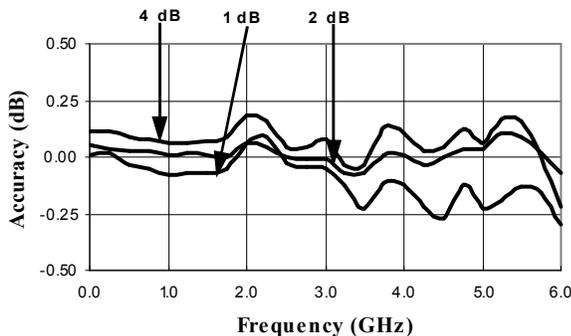
Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

Typical Performance Curves

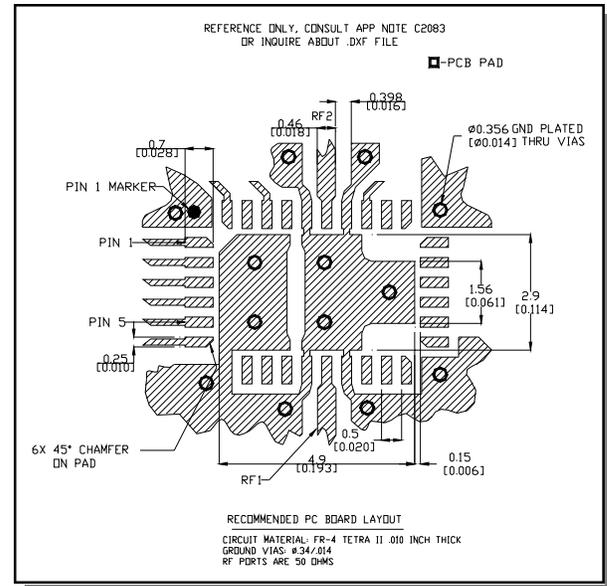
Insertion Loss vs. Frequency



Accuracy (dB) vs. Frequency

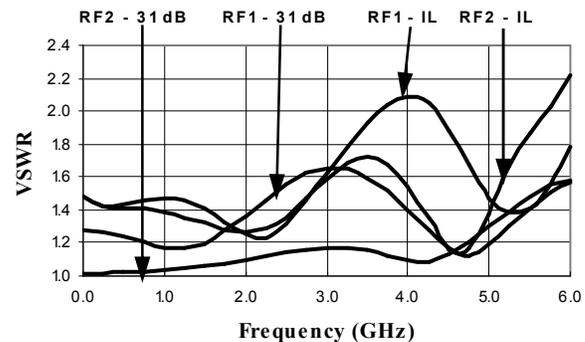


Recommended PCB Configuration⁷

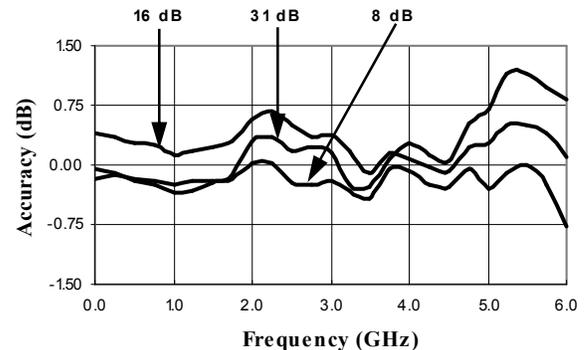


7. Application Note S2083 is available on line at www.macom.com

VSWR vs. Frequency



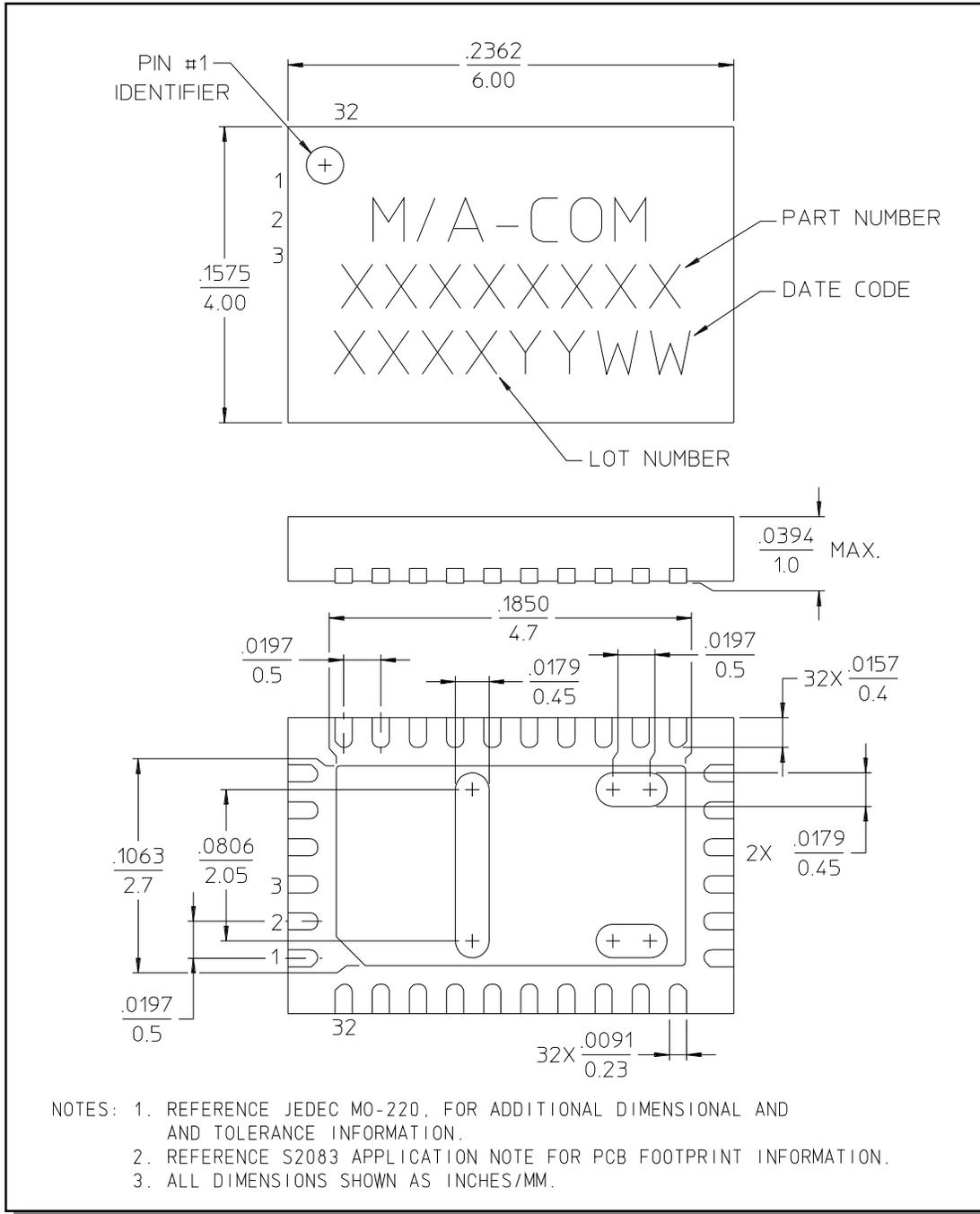
Accuracy (dB) vs. Frequency



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CSP-1, 4 x 6 mm, 32-lead PQFN†



† Reference Application Note M538 for lead-free solder reflow recommendations.